

Product Change Notification

Issue date: 06 Jan 2023

Effective date: 20 Apr 2023

Here's your personalized quality information concerning products our customers and partners purchased from Nexperia.

For more details please contact your respective Nexperia CSR/AM.

CN-202212019F



Change of back side metallization thickness - wave 4

Change **Category**

Location

[X] Wafer Fab Process [X] Wafer Fab Material s [] Wafer Fab	[] Assembl y Process [] Assembl y Materials [] Assembl y	[] Product Marking [] Mechanical Specification [] Packing/Shipping/Labelin g	[] Test Location [] Test Process [] Test Equipmen t	[] Design [] Errata [] Electrical spec./Tes t coverage
Fab	location			

Details of this change

Location

The back side metallization thickness will be changed from 2.25 μm to 1.75 μm .

The change of back side metallization thickness is combined with the introduction of 8 inch wafer diameter for product type PBSS5350D.

Current products: back side metallization thickness 2.25 μ m; 8 inch (where affected) and 6 inch (where affected)

Changed products: back side metallization thickness 1.75 µm; 8 inch

Production on 8 inch wafer diameter implies the use of the respective 8 inch wafer process technology.

SQR_202212019F.pdf: https://qcm.nexperia.com/Document/DOC-548488/SQR_202212019F.pdf

PCNForm.zip: https://qcm.nexperia.com/Document/DOC-548461/PCNForm.zip

DeQuMa.zip: https://qcm.nexperia.com/Document/DOC-548460/DeQuMa.zip

Why do we implement this change?

- To increase efficiency of volume production.
- Capacity expansion in wafer fab
- Continued alignment with world technology trends on state of the art production tools for discrete components

Identification of affected products

Changed product can be identified by date code after implementation. 8 inch products can be identified by a marker on the die surface.

Product availability

Production

Planned first shipment: 01 May 2023

Existing inventory will be shipped until depleted

Sample information

Samples are available upon request

Impact

No impact to the product's functionality anticipated

Data sheet revision

No impact to existing datasheet

Feedback

Your acknowledgement of this change, conform JEDEC J-STD-046, is expected till 05 Feb 2023. Lack of acknowledgement of the PCN constitutes acceptance of the change.

Additional information

View Change Notification Online

Contact and support

For all Quality Notification content inquiries, please contact your local Nexperia Sales Support Team.

For specific questions on this notice or the products affected please contact our specialist directly: pcn@nexperia.com

In case of distribution, please contact you distribution partner.

About Nexperia B.V.

We at Nexperia are the efficiency semiconductor company. We deliver over 90 billion products a year and as such service thousands of global customers, both directly and through our extensive network of channel partners. We are at the heart of billions of electronic devices in the Automotive, Mobile, Industrial, Consumer, Computing, and Communication Infrastructure segments.

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SalesItem_name	SalesItem_orderablePartNumber	SalesOrder_customerPartNumber	ProductType_name	BasicType_description	PackageOutlineVersion_description	PackageType_description	SalesItem_state	SalesItem_customerSpecificIndicator	BusinessLine_description
934056174115	BAT854CW,115	BAT854CW,115	BAT854CW	Schottky barrier (double) (SOT323	SC-70	RFS	No	Bipolar Discretes
934056174135	BAT854CW,135	BAT854CW,135	BAT854CW	Schottky barrier (double) (SOT323	SC-70	RFS	No	Bipolar Discretes
934664480135	BAT854CW-QF		BAT854CW-Q	Schottky barrier (double) (SOT323	SC-70	RFS	No	Bipolar Discretes
934664480115	BAT854CW-QX		BAT854CW-Q	Schottky barrier (double) (SOT323	SC-70	RFS	No	Bipolar Discretes
934056175115	BAT854SW,115	BAT854SW,115	BAT854SW	Schottky barrier (double) (SOT323	SC-70	RFS	No	Bipolar Discretes
934664479115	BAT854SW-QX		BAT854SW-Q	Schottky barrier (double) (SOT323	SC-70	RFS	No	Bipolar Discretes
934056175135	BAT854SWF	BAT854SWF	BAT854SW	Schottky barrier (double) (SOT323	SC-70	RFS	No	Bipolar Discretes
934055946115	PBSS5350D,115	PBSS5350D,115	PBSS5350D	50 V, 3 A PNP low VCEsa	t (SOT457	SC-74	RFS	No	Bipolar Discretes
934055946125	PBSS5350D,125		PBSS5350D	50 V, 3 A PNP low VCEsa	t (SOT457	SC-74	RFS	No	Bipolar Discretes
934055946135	PBSS5350D,135		PBSS5350D	50 V, 3 A PNP low VCEsa	t (SOT457	SC-74	RFS	No	Bipolar Discretes
934664537115	PBSS5350D-QX		PBSS5350D-Q	50 V, 3 A PNP low VCEsa	t (SOT457	SC-74	RFS	No	Bipolar Discretes
934057752115	PMEG4005AEA,115	PMEG4005AEA,115	PMEG4005AEA	Very low VF MEGA School	ttl SOD323	SOD2	RFS	No	Bipolar Discretes
934663853135	PMEG4005AEA-QF		PMEG4005AEA-Q	Very low VF MEGA School	ttl SOD323	SOD2	RFS	No	Bipolar Discretes
934663853115	PMEG4005AEA-QX		PMEG4005AEA-Q	Very low VF MEGA School	ttl SOD323	SOD2	RFS	No	Bipolar Discretes
934663853145	PMEG4005AEA-QZ		PMEG4005AEA-Q	Very low VF MEGA School	ttl SOD323	SOD2	RFS	No	Bipolar Discretes
934057752135	PMEG4005AEAF	PMEG4005AEAF	PMEG4005AEA	Very low VF MEGA School	ttl SOD323	SOD2	RFS	No	Bipolar Discretes
934057752145	PMEG4005AEAZ	PMEG4005AEAZ	PMEG4005AEA	Very low VF MEGA School	ttl SOD323	SOD2	RFS	No	Bipolar Discretes
934057918115	PMEG4010BEA,115	PMEG4010BEA,115	PMEG4010BEA	1 A very low VF MEGA Si	th SOD323	SOD2	RFS	No	Bipolar Discretes
934057918135	PMEG4010BEA,135	PMEG4010BEA,135	PMEG4010BEA	1 A very low VF MEGA Si	th SOD323	SOD2	RFS	No	Bipolar Discretes
934663855135	PMEG4010BEA-QF		PMEG4010BEA-Q	1 A very low VF MEGA Si	:h SOD323	SOD2	RFS	No	Bipolar Discretes
934663855115	PMEG4010BEA-QX		PMEG4010BEA-Q	1 A very low VF MEGA Si	th SOD323	SOD2	RFS	No	Bipolar Discretes